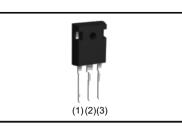


# RGS00TS65HR

650V 50A Field Stop Trench IGBT

V <sub>CES</sub>	650V
I <sub>C (100°C)</sub>	50A
V <sub>CE(sat) (Typ.)</sub>	1.65V
P <sub>D</sub>	326W

#### Outline TO-247N



## Inner Circuit

#### Features

- 1) Low Collector Emitter Saturation Voltage
- 2) Short Circuit Withstand Time 8µs
- 3) Qualified to AEC-Q101
- 4) Pb free Lead Plating ; RoHS Compliant

#### Application

Heater for Automotive

	(2)
(1) O	
	(3)



#### Packaging Specifications

(3)

	Packaging	Tube
	Reel Size (mm)	-
Tuno	Tape Width (mm)	-
Туре	Basic Ordering Unit (pcs)	450
	Packing Code	C11
	Marking	RGS00TS65

# •Absolute Maximum Ratings (at T<sub>c</sub> = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit
Collector - Emitter Voltage		V <sub>CES</sub>	650	V
Gate - Emitter Voltage		V <sub>GES</sub>	±30	V
Collector Current	$T_{\rm C}$ = 25°C	Ι <sub>C</sub>	88	Α
Collector Current	T <sub>C</sub> = 100°C	Ι <sub>C</sub>	50	Α
Pulsed Collector Current		I <sub>CP</sub> *1	150	Α
Dower Dissinction	$T_{\rm C}$ = 25°C	P <sub>D</sub>	326	W
Power Dissipation	T <sub>C</sub> = 100°C	P <sub>D</sub>	163	W
Operating Junction Temperature		Tj	-40 to +175	°C
Storage Temperature		T <sub>stg</sub>	-55 to +175	°C

\*1 Pulse width limited by T<sub>imax.</sub>

#### •Thermal Resistance

Parameter	Symbol	Values			Unit
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal Resistance IGBT Junction - Case	$R_{\theta(j\text{-}c)}$	-	-	0.46	°C/W

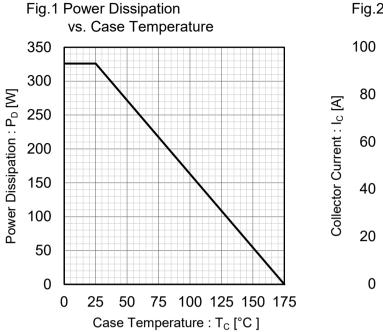
### ●IGBT Electrical Characteristics (at T<sub>i</sub> = 25°C unless otherwise specified)

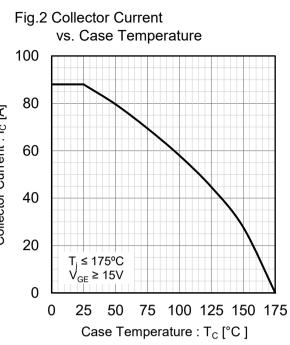
Parameter	Symbol	Conditions	Values			Unit
Farameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector - Emitter Breakdown Voltage	BV <sub>CES</sub>	I <sub>C</sub> = 10μΑ, V <sub>GE</sub> = 0V	650	-	-	V
		V <sub>CE</sub> = 650V, V <sub>GE</sub> = 0V,				
Collector Cut - off Current	I <sub>CES</sub>	T <sub>j</sub> = 25°C Tj = 175°C <sup>*2</sup>	-	-	10	μA
		Tj = 175°C <sup>*2</sup>	-	-	5	mA
Gate - Emitter Leakage Current	I <sub>GES</sub>	$V_{GE}$ = ±30V, $V_{CE}$ = 0V	-	-	±200	nA
Gate - Emitter Threshold Voltage	$V_{\text{GE(th)}}$	V <sub>CE</sub> = 5V, I <sub>C</sub> = 2.5mA	5.0	6.0	7.0	V
		I <sub>C</sub> = 50A, V <sub>GE</sub> = 15V,				
Collector - Emitter Saturation Voltage	V <sub>CE(sat)</sub>	T <sub>j</sub> = 25°C	-	1.65	2.10	V
		T <sub>j</sub> = 175°C	-	2.15	-	V

# •IGBT Electrical Characteristics (at $T_j = 25^{\circ}C$ unless otherwise specified)

Deremeter	Symbol	Conditions	Values			1.1	
Parameter			Min.	Тур.	Max.	Unit	
Input Capacitance	C <sub>ies</sub>	V <sub>CE</sub> = 30V,	-	1568	-		
Output Capacitance	C <sub>oes</sub>	V <sub>GE</sub> = 0V,	-	134	-	pF	
Reverse transfer Capacitance	C <sub>res</sub>	f = 1MHz	-	23	-		
Total Gate Charge	Q <sub>g</sub>	V <sub>CE</sub> = 300V,	-	58	-		
Gate - Emitter Charge	Q <sub>ge</sub>	I <sub>C</sub> = 50A,	-	15	-	nC	
Gate - Collector Charge	Q <sub>gc</sub>	V <sub>GE</sub> = 15V	-	24	-		
Turn - on Delay Time	t <sub>d(on)</sub>		-	36	-	ns	
Rise Time	t <sub>r</sub>	I <sub>C</sub> = 50A, V <sub>CC</sub> = 400V, V <sub>GE</sub> = 15V, R <sub>G</sub> = 10Ω,	-	21	-		
Turn - off Delay Time	t <sub>d(off)</sub>	$T_i = 25^{\circ}C$	-	115	-		
Fall Time	t <sub>f</sub>	Inductive Load	-	91	-		
Turn - on Switching Loss	E <sub>on</sub>	*E <sub>on</sub> include diode reverse recovery	-	1.46	-	mJ	
Turn - off Switching Loss	E <sub>off</sub>	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	-	1.29	-		
Turn - on Delay Time	t <sub>d(on)</sub>		-	37	-		
Rise Time	t <sub>r</sub>	I <sub>C</sub> = 50A, V <sub>CC</sub> = 400V, V <sub>GE</sub> = 15V, R <sub>G</sub> = 10Ω,	-	33	-	ns	
Turn - off Delay Time	t <sub>d(off)</sub>	$T_i = 175^{\circ}C$	-	145	-		
Fall Time	t <sub>f</sub>	Inductive Load	-	147	-		
Turn - on Switching Loss	E <sub>on</sub>	*E <sub>on</sub> include diode reverse recovery	-	1.97	-	ml	
Turn - off Switching Loss	E <sub>off</sub>	·····,	-	1.85	-	- mJ	
Reverse Bias		$I_{\rm C} = 150 {\rm A}, V_{\rm CC} = 520 {\rm V},$				-	
Safe Operating Area	RBSOA	V <sub>P</sub> = 650V, V <sub>GE</sub> = 15V, R <sub>G</sub> = 50Ω, T <sub>i</sub> = 175°C	FULL SQUARE				
Short Circuit Withstand Time	t <sub>sc</sub>	V <sub>CC</sub> ≤ 360V, V <sub>GE</sub> = 15V, T <sub>j</sub> = 25°C	8	-	-	μs	
Short Circuit Withstand Time	t <sub>sc</sub> *2	V <sub>CC</sub> ≤ 360V, V <sub>GE</sub> = 15V, T <sub>j</sub> = 150°C	6	-	-	μs	

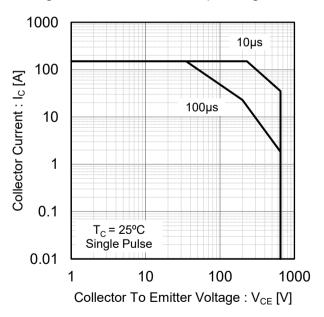
\*2 Design assurance without measurement

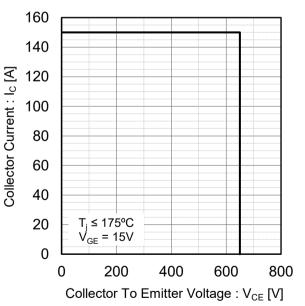




# Fig.3 Forward Bias Safe Operating Area







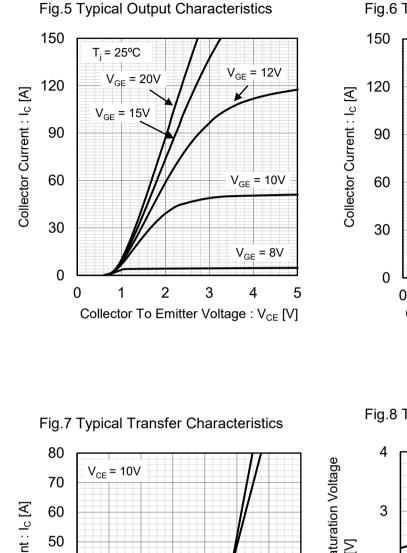


Fig.6 Typical Output Characteristics

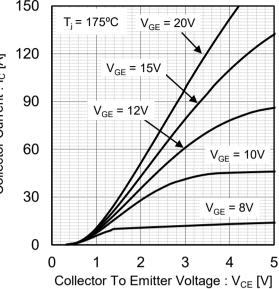
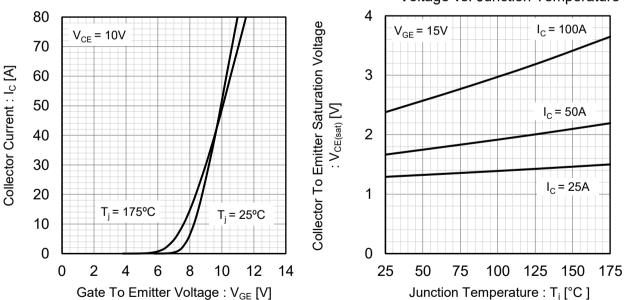
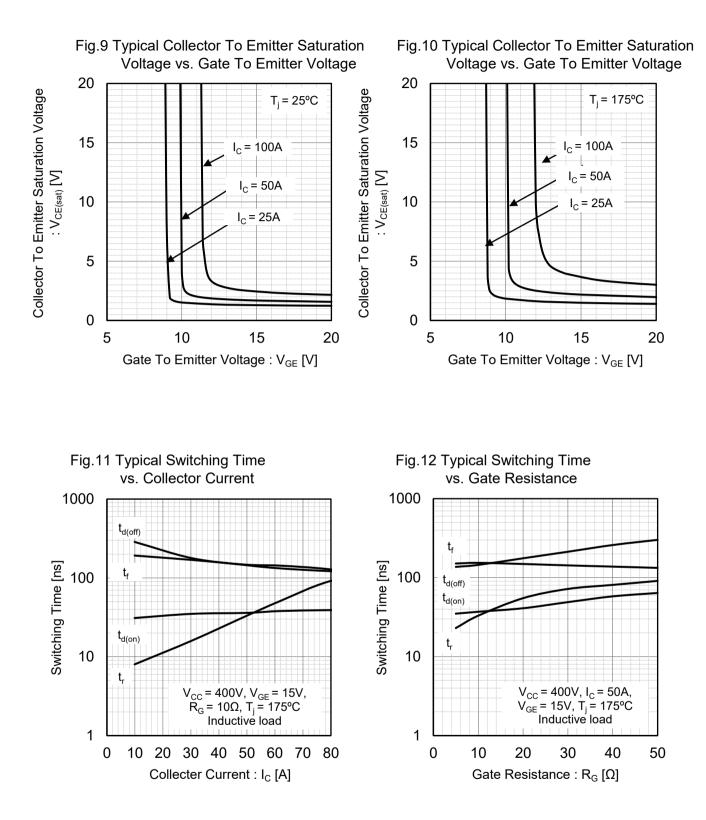
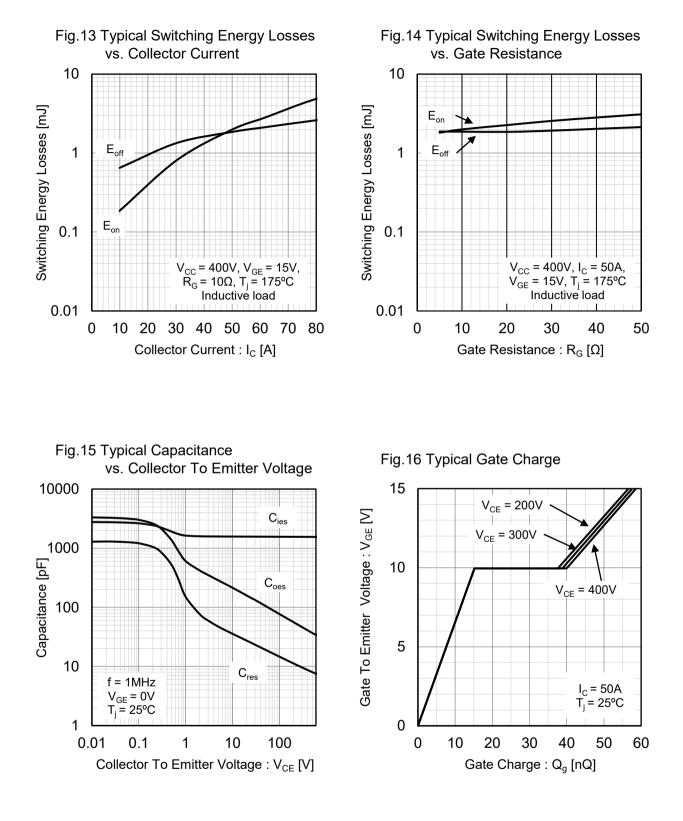


Fig.8 Typical Collector To Emitter Saturation Voltage vs. Junction Temperature







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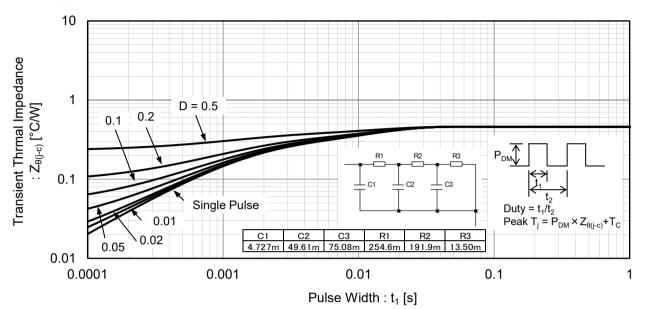


Fig.17 IGBT Transient Thermal Impedance



#### Inductive Load Switching Circuit and Waveform

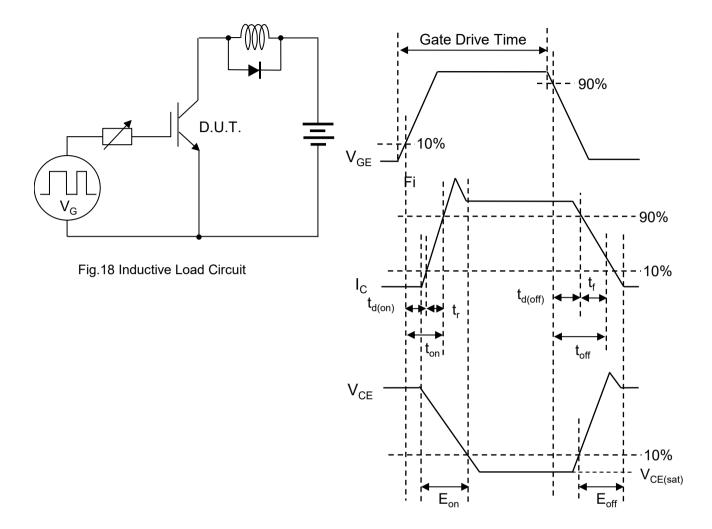


Fig.19 Inductive Load Waveform



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